



PRODUCT DATASHEET



- EMC SMD Top View
- ▶ 3838 3.3t Series
- Infrared (IR) 850nm







FEATURES:

- Package: Black Ceramic Dual Junction with Asymmetric Lens
- Forward Current: 1000mA
- Forward Voltage (typ.): 3.4V
- Radiant Power (typ.): 1200mW@1A
- Radiant Intensity (typ.): 1500mW/sr@1A
- Colour: Infrared (IR)
- Peak Wavelength (typ.): 850nm
- Viewing angle: X:40° / Y: 25°
- Materials:
 - Resin: Silicon (Water Clear)
 - L/T Finish: Ag plated
- Operating Temperature: -40~+125°C
- Storage Temperature: -40~+125°C
- Grouping parameters:
 - Forward Voltage
 - Radiant Power
 - Peak Wavelength
- Soldering methods: Reflow
- Preconditioning: MSL2 according to J-STD020
- Corrosion Robustness Class: 3B



NOF60S77BF

- **APPLICATIONS:**
- Automotive
- Security Camera
- Motion Detection
- Night Viewer
- Surveillance
- Data Communication





CHARACTERISTICS:

Parameter	Symbol	Ratings	Unit
DC Forward Current	IF	1000	mA
Pulse Forward Current	Ifp	5	А
Power Consumption	P _{tot}	3.8	W
Reverse Voltage	VR	5	V
Reverse Current @5V	IR	10	μΑ
Junction Temperature	Tj	145	°C
Thermal Resistance Junction to Solder Point	R _{th}	11	K/W
Electrostatic Discharge (HBM: MIL-STD-883 C 2)	ESD	2	kV
Operating Temperature	T _{OPR}	-40~+125	°C
Storage Temperature	Тѕтб	-40~+125	°C
Soldering Temperature	T _{SOL}	260	°C

Absolute Maximum Characteristics (Ta=25°C)

Electrical & Optical Characteristics (Ta=25°C, I_F=1A, t_p=10ms)

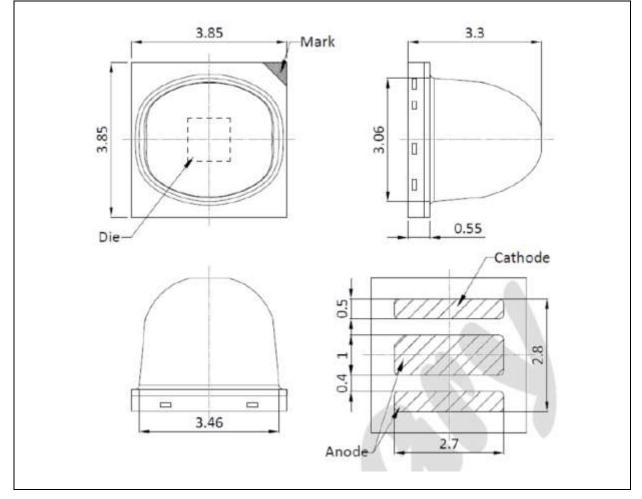
Parameter		Sumbol	Values			Unit	Test
		Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Voltage		V _F		3.4	3.8	V	I _F =1A
Radiant Power		Φe		1200	1300	mW	IF=1A
Radiant Intensity		l _e		1500	1800	mW/sr	I _F =1A
Peak Wavelength		Лρ		850		nm	IF=1A
Spectral Bandwidth		Δλ		40		nm	IF=1A
Viewing Angle	х	2 θ 1/2		45		deg	IF=1A
	Y			25			

1. Radiant Power (P_0) ±10%, Forward Voltage (V_F) ±0.1V, Viewing angle(2 $\theta_{1/2}$) ±10°



OUTLINE DIMENSION:

Package Dimension:



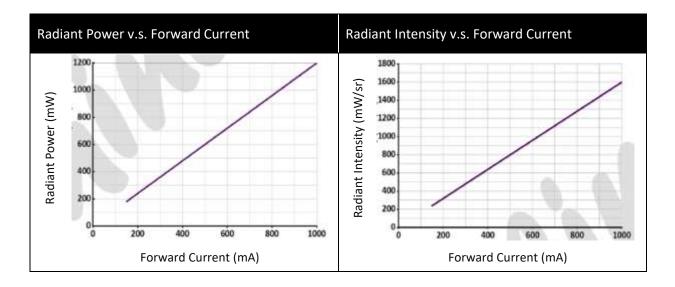
1. All dimensions are in millimetre (mm).

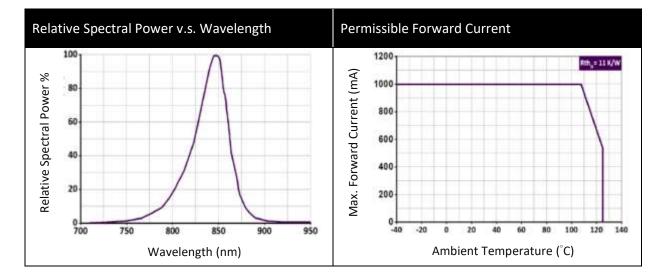
3

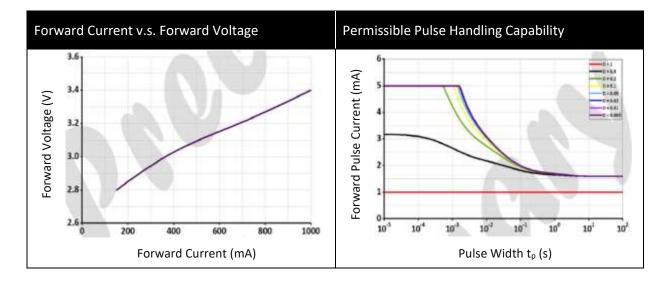
2. Tolerance ±0.13mm, unless otherwise noted.



ELECTRO-OPTICAL CHARACTERISTICS:

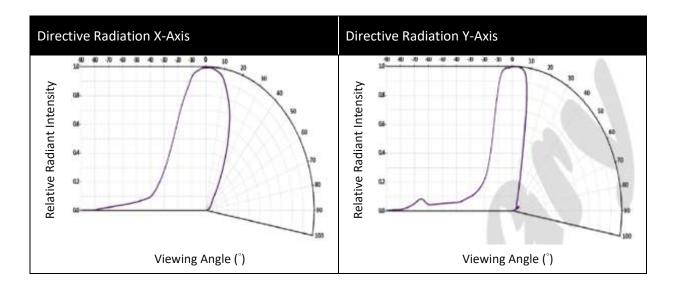








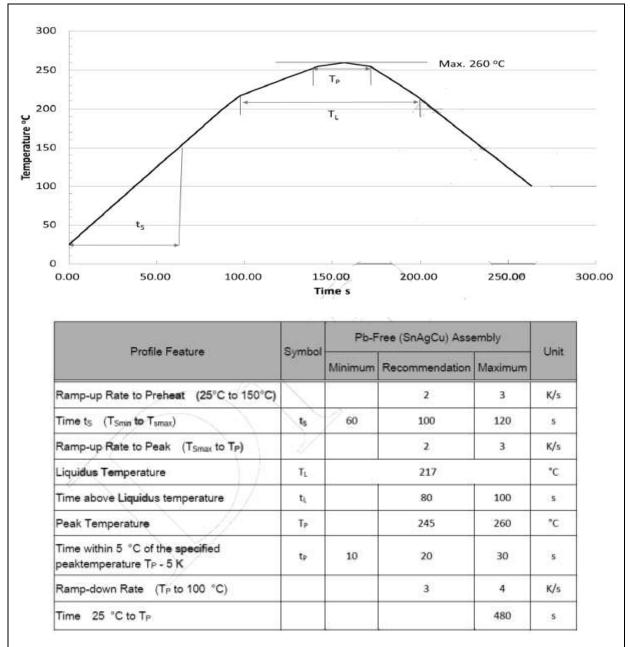
ELECTRO-OPTICAL CHARACTERISTICS:



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RECOMMENDED SOLDERING PROFILE:



Reflow Lead-free Solder:

Note:

- 1. Maximum reflow soldering: 2 times.
- 2. Recommended soldering temperature is 245°C. The maximum soldering temperature should be limited to 260°C.
- 3. Before, during, and after soldering, should not apply stress on the components and PCB board.

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PRECAUTIONS OF USE:



Storage:

It is recommended to store the products in the following conditions:

- Humidity: 60% R.H. Max.
- Temperature: 5°C~30°C (41°F ~86°F).

Shelf life in sealed bag: 12 months at 5°C~30°C and <60% R.H.

Once the package is opened, the products should be used within a week. Otherwise, they should be kept in a damp-proof box with descanting agent <10% R.H. and apply baking before use.

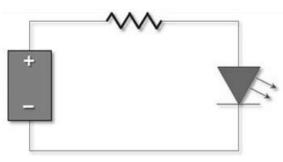
Baking:

It is recommended to bake the LED before soldering if the pack has been unsealed for longer than 24hrs. The suggested baking conditions are as followings:

• 60±3°C x 24hrs and <5%RH, taped / reel package.

It's normal to see slight color fading of carrier (light yellow) after baking in process.

Testing Circuit:



Must apply resistor(s) for protection (over current proof).

Cleaning:

Use alcohol-based cleaning solvents such as isopropyl alcohol to clean the LED carrier / package. Avoid putting any stress force directly on to the LED lens.

ESD (Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing the LED all time. All devices, equipment, machinery, work tables, and storage racks must be properly grounded.

In the events of manual working in process, make sure the devices are well protected from ESD at any time.



REVISION RECORD:

Version	Date	Summary of Revision
A1.0	22/05/2022	Datasheet set-up.